

Bernard GELLOZ

Position	Associate Professor
Lab/Group	Nanomagnetism and Spintronics Group (J Lab)
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Education and Degrees

- 1991 *Bachelor of Physics*, Fourier University, Grenoble I, France.
- 1993 *Master of Physics*, Fourier University, Grenoble I, France.
- 1997 *Ph.D. in Condensed Matter Physics* (with highest level of distinction), Spectrometry Laboratory, Fourier University, Grenoble I, France.
- 2007 *French Habilitation*, Fourier University, Grenoble I, France.

Positions

- 1997 *Postdoctoral Research Fellow (Japan, JSPS)*, Faculty of Technology, Department of Electrical & Electronic Engineering, Tokyo University of Agriculture and Technology
- 2000 *Postdoctoral Research Fellow (Japan, STA)*, Semiconductor Laboratory, The Institute of Physical and Chemical Research (RIKEN)
- 2001 *Assistant Professor*, Faculty of Technology, Department of Electrical & Electronic Engineering, Tokyo University of Agriculture and Technology
- 2011 *Designated Associate Professor (G30)*, Graduate School of Engineering, Nagoya University
- 2019 *Designated Associate Professor (G30)*, Graduate School of Science, Nagoya University
- 2020 *Associate Professor*, Graduate School of Science, Nagoya University

Honors

- 2003-2005 “Young Research Fellowship II” from the 21st Century COE (Center Of Excellence) Program on Future Nano-materials.

2003-2004 “Marubun Research and Encouragement Award” from the Marubun Research Promotion Foundation.

2000-2001 STA (Science and Technology Agency) Fellow.

1997-1999 JSPS (Japan Society for the Promotion of Science) Fellow.

Research

porous silicon, silicon nanocrystals, luminescence, electroluminescence, photonics, plasmonics.

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List of Publications

[GoogleScholar \(link\)](#)